钍地半导体
Tudi Semiconductor

UC2842A/43/44/45
UC3842A/43/44/45

CURRENT MODE PWM CONTROLLER

DESCRIPTION

The UC284X A and UC384x A are fixed frequency current mode

PWM controller. Strengthen the compressive current

They are specially designed for OFF–Line and DC to DC convert er applications with a minimal external components. Internally impl emented circuits include a trimmed oscillator for precise duty cycl e control, a temper ature compensated reference, high gain error a mplifier, current nsing comparator, and a high current totem pole outp ut ideally suited

for driving a power MOSFET. Protection circuitry includes built un der voltage lockout and current limiting.

Examples

Strengthen the compressive current

The corresponding thresholds for the UC2843A/45, UC38 43/45 are 8.4 V (on) and 7.6V (off).The UC2842A/43, UC3842 /43 can operate within 100% duty cycle.

TheUC2842/44,UC3842/44haveUVLOthresholdsof16V(on)a nd10V (off).

FEATURES

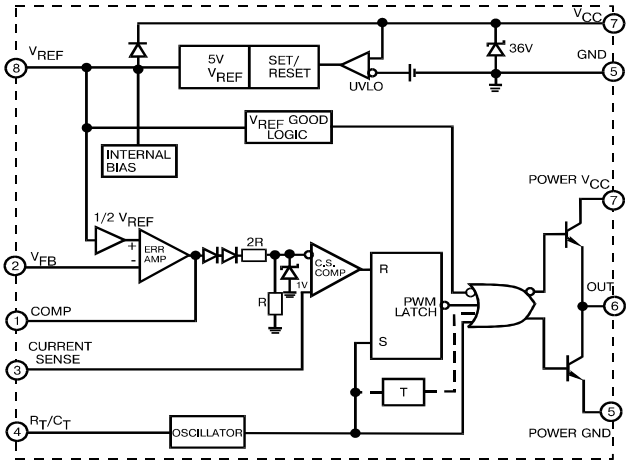
- Low Start-Up and Operating Current
- High Current Totem Pole Output
- Under voltage Lockout With Hysteresis
- Operating Frequency Up To 500KHz

The UC2842/44, UC3842/44 have UVLO thresholds of 16 V (on) and 10 V (off).

型号	封装	私印	UVLO On	UVLO OFF	Maximum DutyCycle
UC3842AD8TR-TUDI	SOP8	UC3842A	16.0V	10.0V	≤100%
UC2842AD8TR-TUDI	SOP8	UC2842A	16.0V	10.0V	≤100%
UC2842AQD8R-TUDI	SOP8	UC2842AQ	16.0V	10.0V	<100
UC2843AD8TR-TUDI	SOP8	UC2843A	8.4V	7.6V	≤50%
UC2843AQD8RQ1-TUDI	SOP8	UC2843AQ	8.4V	7.6V	<50
UC2844AD8TR-TUDI	SOP8	UC2844A	16.0V	10.0V	≤100%
UC2844AQD8R-TUDI	SOP8	UC2844AQ	16.0V	10.0V	<100
UC2845AD8TR-TUDI	SOP8	UC2845A	8.4V	7.6V	<50
UC2845AQD8R-TUDI	SOP8	UC2845AQ	8.4V	7.6V	<50
UC3843AD8TR-TUDI	SOP8	UC3843A	8.4V	7.6V	≤50%
UC3844AD8TR-TUDI	SOP8	UC3844A	16.0V	10.0V	≤100%
UC3845AD8TR-TUDI	SOP8	UC3845A	8.4V	7.6V	≤50%
UC2842AN-TUDI	DIP8	UC2842AN	16.0V	10.0V	<100
UC2843AN-TUDI	DIP8	UC2843AN	8.4V	7.6V	<50
UC2844AN-TUDI	DIP8	UC2844AN	16.0V	10.0V	<100
UC2845AN-TUDI	DIP8	UC2845AN	8.4V	7.6V	<50
UC3842AN-TUDI	DIP8	UC3842AN	16.0V	10.0V	≤100%
UC3843AN-TUDI	DIP8	UC3843AN	8.4V	7.6V	≤50%
UC3844AN-TUDI	DIP8	UC3844AN	16.0V	10.0V	≤100%
UC3845AN-TUDI	DIP8	UC3845AN	8.4V	7.6V	≤50%

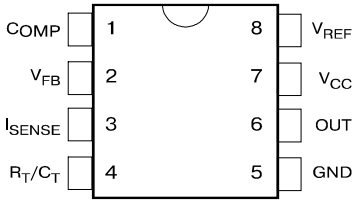
BLOCK DIAGRAM

(toggle flip flop used only in UC2844/45, UC3844/45)



PIN CONNECTION

(TOP VIEW)



PIN FUNCTION

N	FUNCTION	DESCRIPTION
1	COMP	This pin is the Error Amplifier output and is made for loop compensation.
2	V_{FB}	This is the inverting input of the Error Amplifier. It is normally connected to the switching power supply output through a resistor divider.
3	I_{SENSE}	A voltage proportional to inductor current is connected to this input. The PWM uses this information to terminate the output switch conduction.
4	R_T/C_T	The oscillator frequency and maximum Output duty cycle are programmed by connecting resistor R_T to V_{ref} and capacitor C_T to ground.
5	GROUND	This pin is the combined control circuitry and power ground.
6	OUTPUT	This output directly drives the gate of a power MOSFET. Peak currents up to 1A are sourced and sink by this pin.
7	V_{CC}	This pin is the positive supply of the integrated circuit.
8	V_{ref}	This is the reference output. It provides charging current for capacitor C_T through resistor R_T.

Absolute Maximum Ratings

Characteristic	Symbol	Value	Unit
Supply Voltage (low impedance source)	V_{CC}	30	V
Output Current	I_O	±1	A
Input Voltage (Analog Inputs pins 2,3)	V_I	−0.3 to 5.5	V
Error Amp Output Sink Current	$I_{SINK\ (E.A)}$	10	mA
Power Dissipation (T_A=25°C)	P_O	1	W
Storage Temperature Range	Tstg	-65 to150	°C
Lead Temperature (soldering 5 sec.)	T_L	260	°C

Electrical characteristics (*V_{CC}=15V, R_T=10kΩ, C_T=3.3nF, T_A=0^{0}C to +70^{0}C, unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ	Max	Unit
Reference Section						
Reference Output Voltage	V_{REF}	T_J = 25°C, I_{REF} = 1 mA	4.9	5.0	5.1	V
Line Regulation	ΔV_{REF}	12V ≤ V_{CC} ≤ 25 V		6.0	20	mV
Load Regulation	ΔV_{REF}	1 mA ≤ I_{REF} ≤ 20mA		6.0	25	
Short Circuit Output Current	I_{SC}	T_A = 25°C		-100	-180	mA
Oscillator Section						
Oscillation Frequency	f	T_J = 25°C	47	52	57	KHz
Frequency Change with Voltage	$\Delta f/\Delta V_{CC}$	12V ≤ V_{CC} ≤ 25 V		0.05	1.0	%
Oscillator Amplitude	$V_{(OSC)}$	(peak to peak)		1.6		V
Error Amplifier Section						
Input Bias Current	I_{BIAS}	V_{FB}=3V		-0.1	-2	μA
Input Voltage	$V_{I(E.A)}$	V_{pin1} = 2.5V	2.42	2.5	2.58	V
Open Loop Voltage Gain	A_{VOL}	2V ≤ V_0 ≤ 4V	65	90		dB
Unity Gain Bandwidth	UGBW	T_J=25^{0}C, Note 3	0.5	0.6		MHz
Power Supply Rejection Ratio	PSRR	12V ≤ V_{CC} ≤ 25 V	60	70		dB
Output Sink Current	I_{SINK}	V_{pin2} = 2.7V, V_{pin1} = 1.1V	2	7		mA
Output Source Current	I_{SOURCE}	V_{pin2} = 2.3V, V_{pin1} = 5V	-0.5	-1.0		mA
High Output Voltage	V_{OH}	V_{pin2} = 2.3V, R_L = 15KΩ to GND	5.0	6.0		V
Low Output Voltage	V_{OL}	V_{pin2} = 2.7V, R_L = 15KΩ to PIN 8		0.8	1.1	
Current Sense Section						
Gain	G_V	(Note 1 & 2)	2.85	3.0	3.15	V/V
Maximum Input Signal	$V_{I(MAX)}$	V_{pin1} = 5V (Note1)	0.9	1.0	1.1	V
Supply Voltage Rejection	SVR	12V ≤ V_{CC} ≤ 25 V (Note 1)		70		dB
Input Bias Current	I_{BIAS}	V_{pin3} = 3V		-3.0	-10	μA
Output Section						
Low Output Voltage	V_{OL}	I_{SINK} = 20 mA		0.08	0.4	V
		I_{SINK} = 200 mA		1.4	2.2	
High Output Voltage	V_{OH}	I_{SINK} = 20 mA	13	13.5		
		I_{SINK} = 200 mA	12	13.0		
Rise Time	t_R	T_J = 25°C, C_L = 1nF (Note 3)		45	150	nS
Fall Time	t_F	T_J = 25°C, C_L = 1nF (Note 3)		35	150	
Undervoltage Lockout Section						
Start Theshold	$V_{TH(ST)}$	UC2842/44,UC3842/44	14.5	16.0	17.5	V
		UC2843/45,UC3843/45	7.8	8.4	9.0	
Min. Operating Voltage	$V_{OPR(min)}$	UC2842/44,UC3842/44	8.5	10	11.5	V
(After Turn On)		UC2843/45,UC3843/45	7.0	7.6	8.2	
PWM Section						
Max. Duty Cycle	$D_{(MAX)}$	UC2842/43,UC3842/43	95	97	100	%
		UC2844/45,UC3844/45	47	48	50	
Min. Duty Cycle	$D_{(MAX)}$				0	
Total Standby Current						
Start−Up Current	I_{ST}	UC3842/43/44/45		0.17	0.3	mA
Operating Supply Current	$I_{CC\ (OPR)}$	V_{pin3} = V_{pin2} = 0V		13	17	
Zener Voltage	V_Z	I_{CC}=25 mA	30	38		V

* Adjust V_{CC} above the start threshold before setting it to 15V.
Note 1: Parameter measured at trip point of latch with V_{pin2}=0.
Note 2: Gain defined as A=$\Delta V_{pin1}/\Delta V_{pin3}$; 0 ≤ V_{pin3} ≤ 0.8V.
Note 3: These parameters, although guaranteed, are not 100% tested in production.

APPLICATION INFORMATION

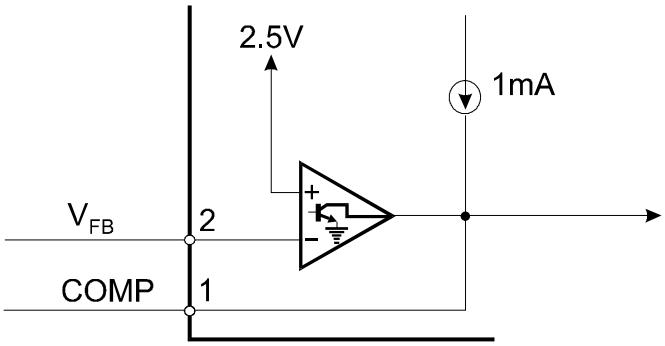
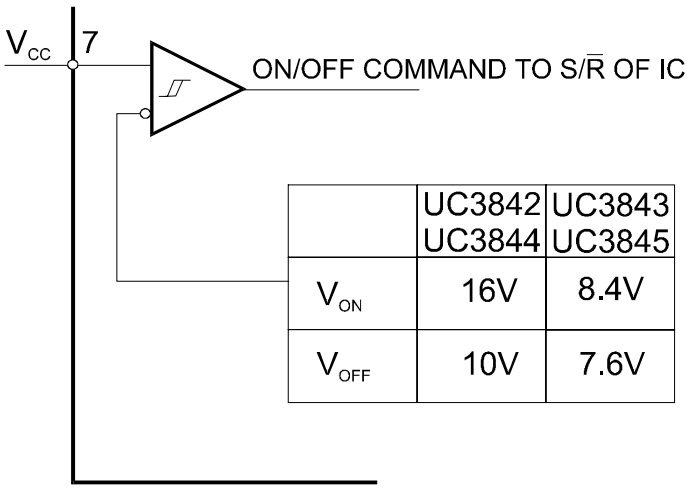
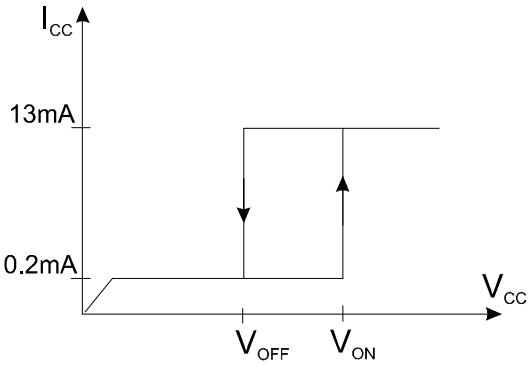


Figure 1. Error Amp Configuration



	UC3842 UC3844	UC3843 UC3845
V_{ON}	16V	8.4V
V_{OFF}	10V	7.6V



During UVLO, the Output is low

Figure 2. Under voltage Lockout

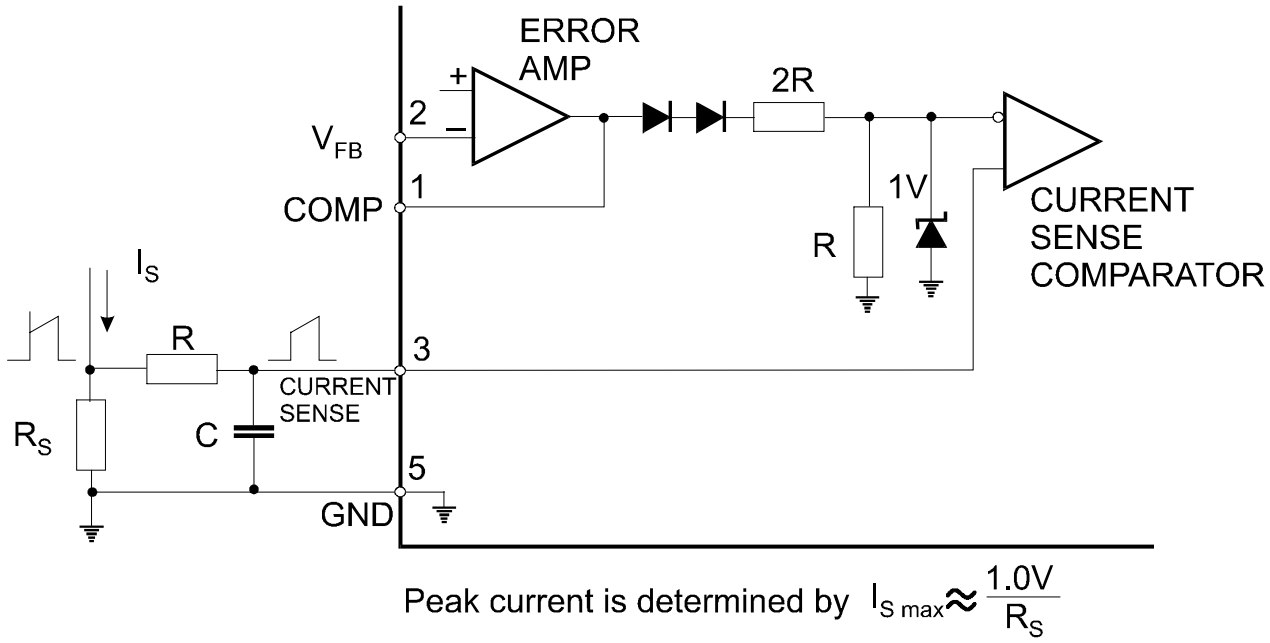


Figure 3. Current Sense Circuit

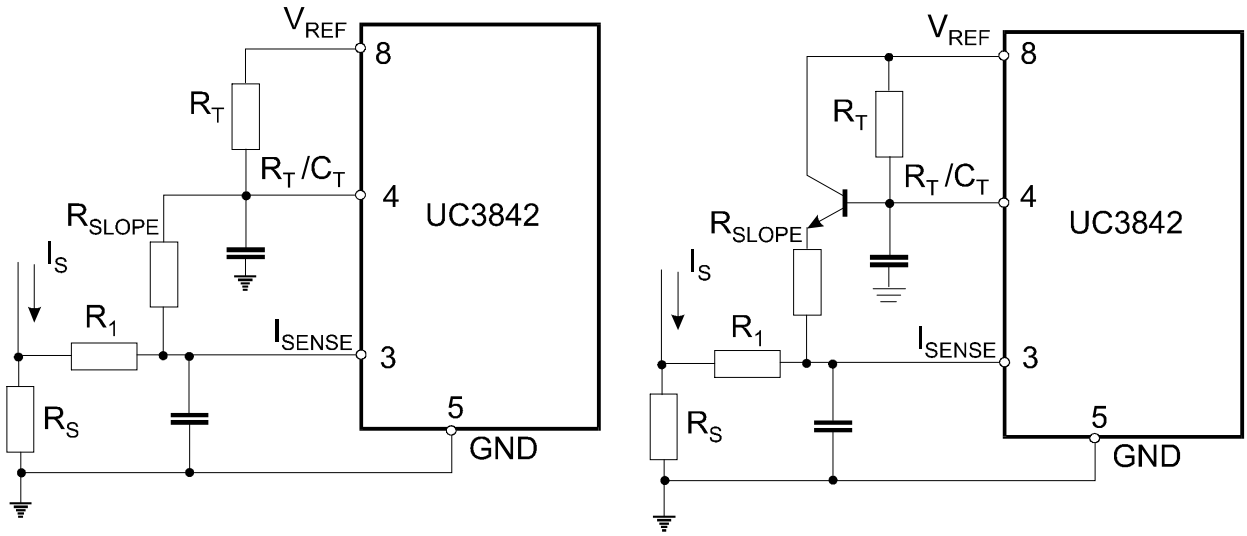
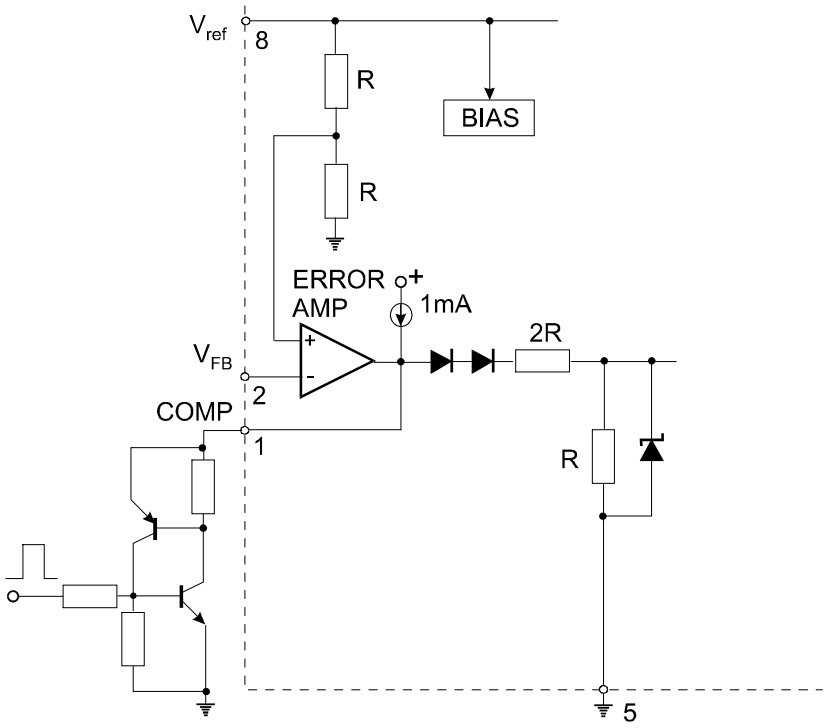
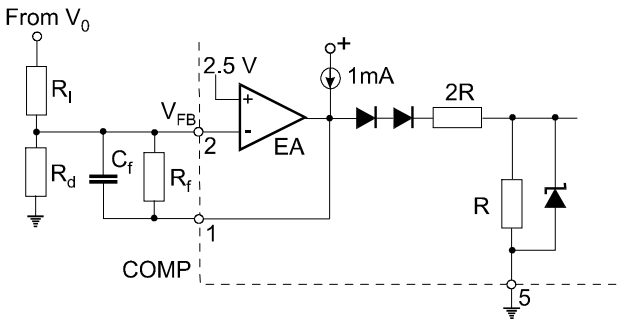


Figure 4. Slope Compensation Techniques

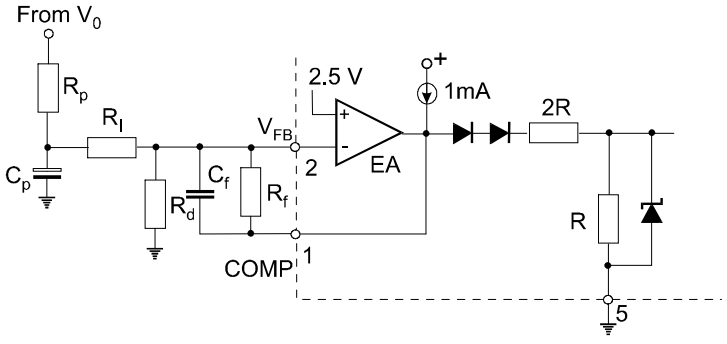


SCR must be selected for a holding current of less than 0.5mA.
The simple two transistor circuit can be used in place of the SCR as shown.

Figure 5. Latched Shutdown



Error Amp compensation circuit for stabilizing any current-mode topology except for boost and flyback converters operating with continuous inductor current.



Error Amp compensation circuit for stabilizing current-mode boost and flyback topologies operating with continuous inductor current.

Figure 6. Error Amplifier Compensation

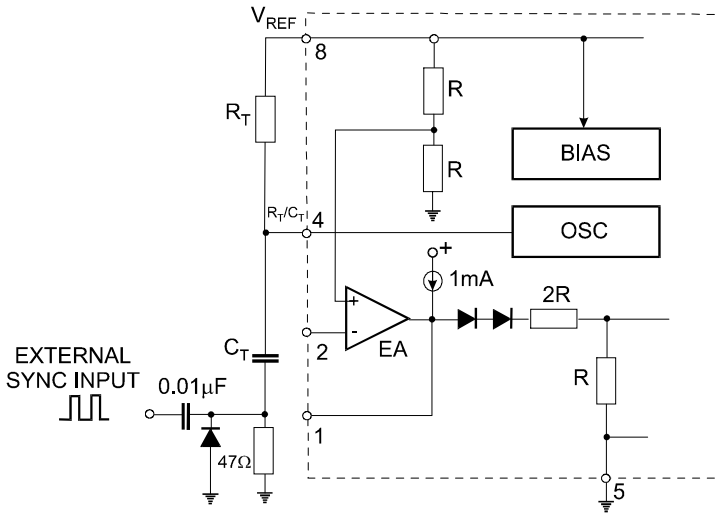


Figure 7. External Clock Synchronization

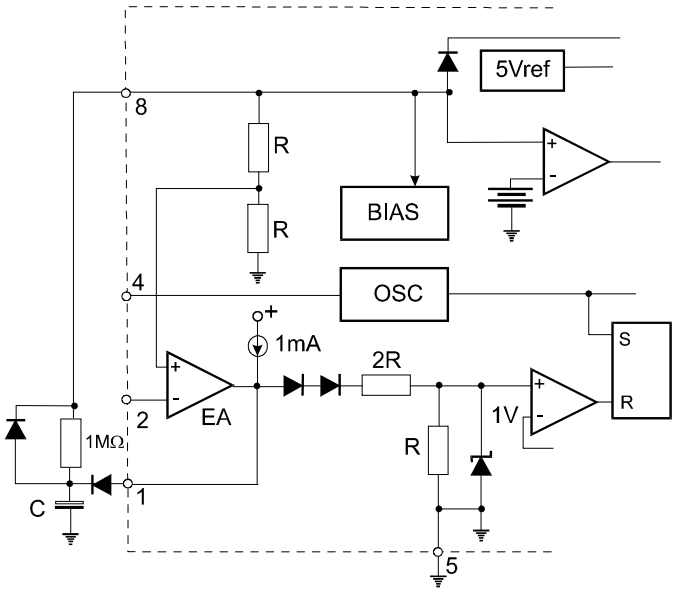


Figure 8. Soft-Start Circuit

TYPICAL PERFORMANCE CHARACTERISTICS

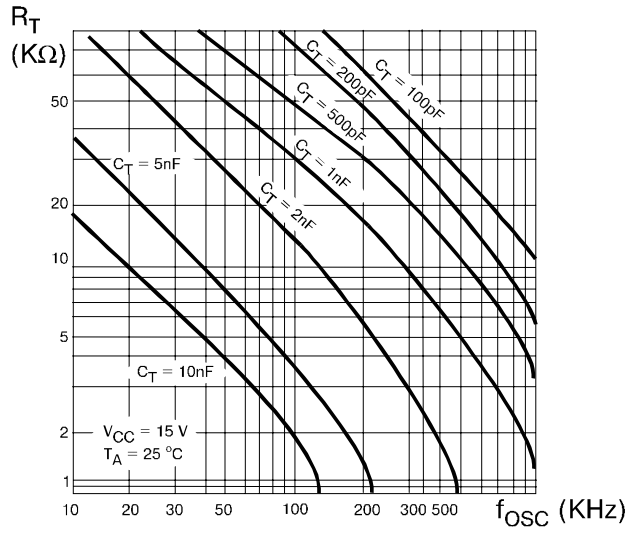


Figure 1. Timing Resistor vs. Oscillator Frequency

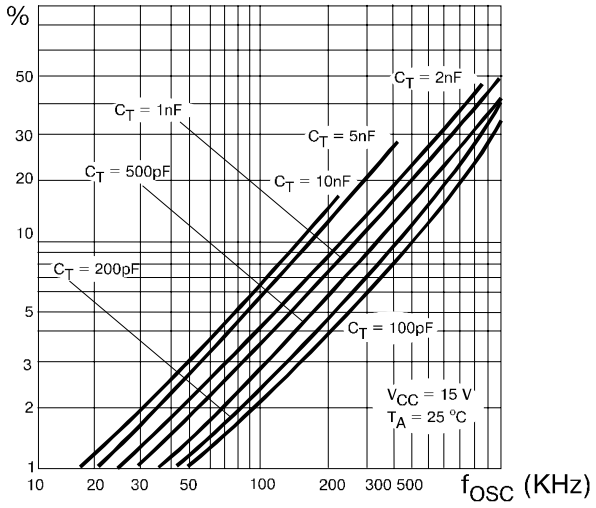


Figure 2. Output Dead-Time vs. Oscillator Frequency

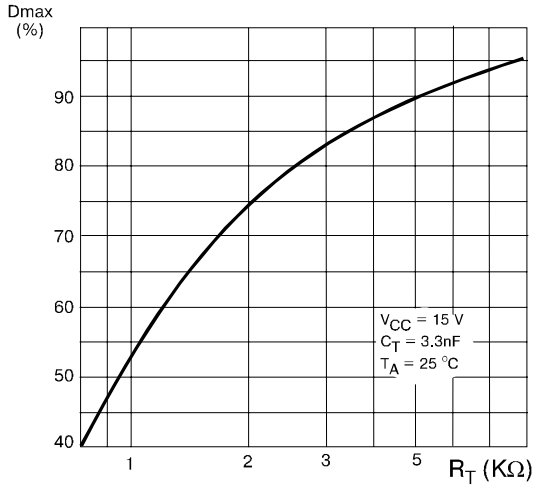


Figure 3. Maximum Output Duty Cycle vs. Timing Resistor (UC3842/43)

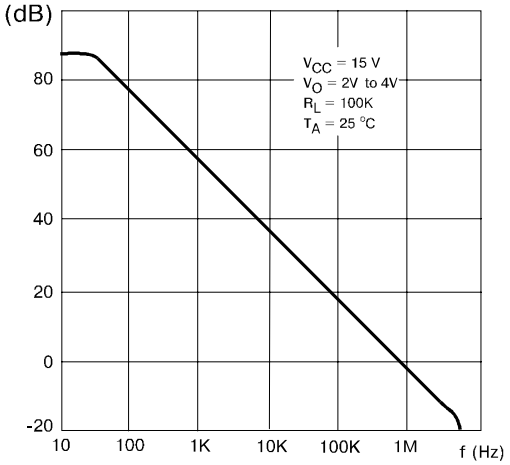


Figure 4. Error Amp Open-Loop Gain vs. Frequency

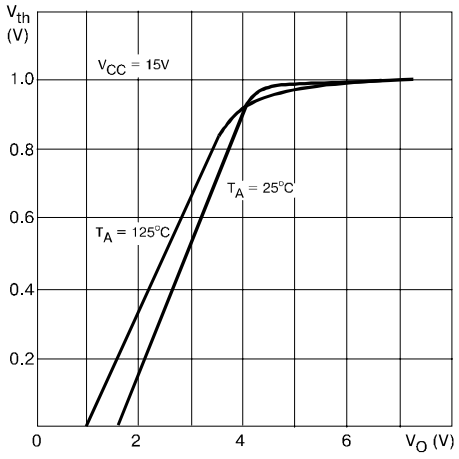


Figure 5. Current Sense Input Threshold vs. Error Amp Output Voltage

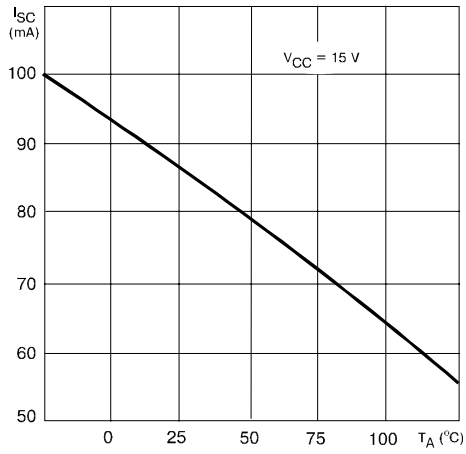


Figure 6. Reference Short Circuit Current vs. Temperature

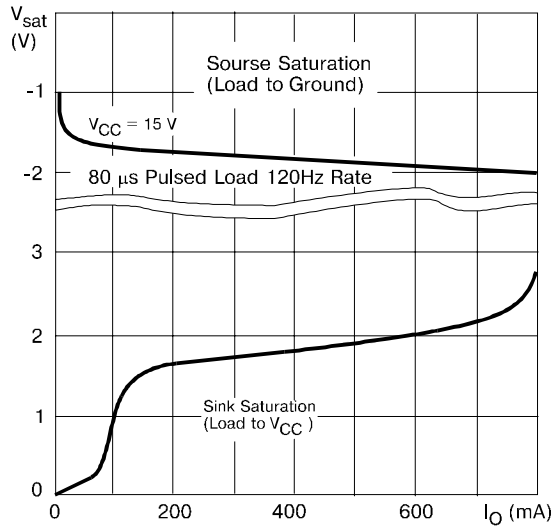


Figure 7. Output Saturation Voltage vs. Load Current
T_A = 25°C

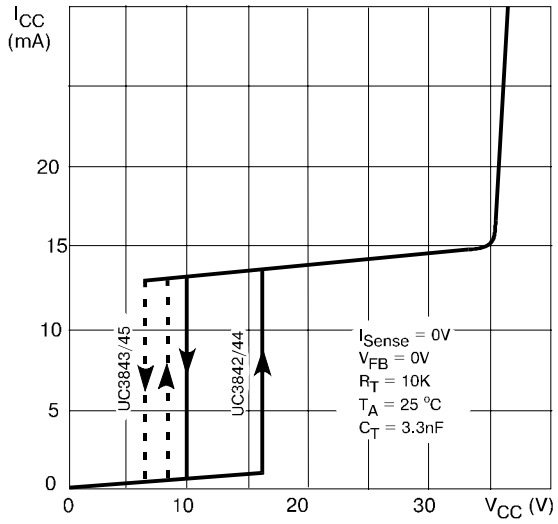


Figure 8. Supply Current vs. Supply Voltage

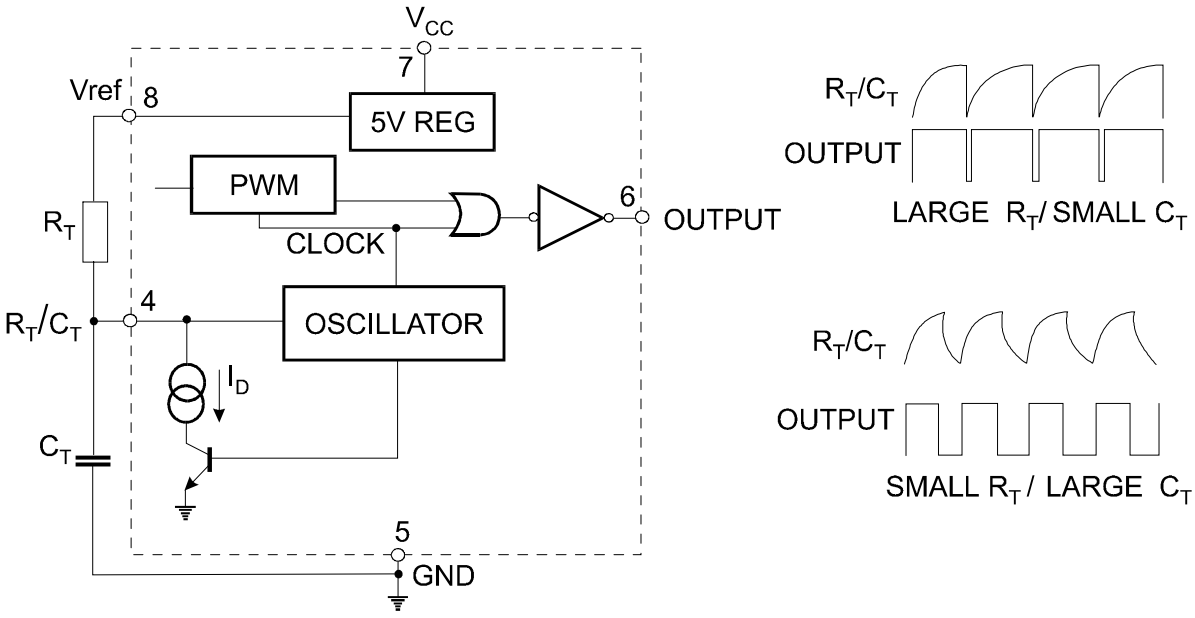
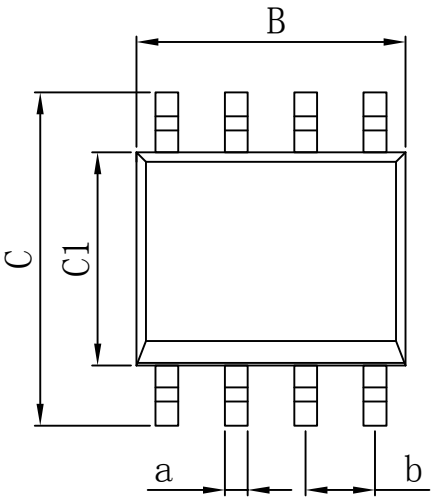
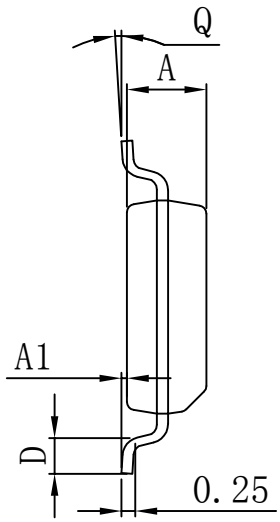


Figure 9. Oscillator and Output Waveforms

PACKAGE

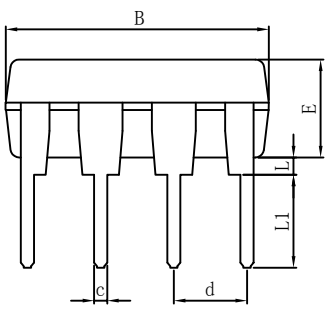
SOP8

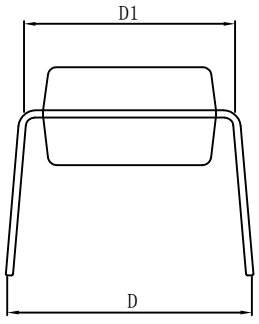


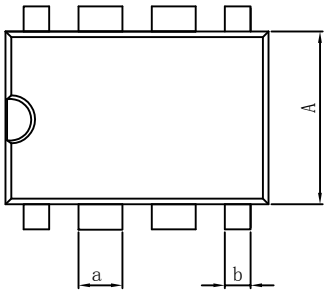


Dimensions In Millimeters					
Symbol :	Min :	Max :	Symbol :	Min :	Max :
A	1.225	1.570	D	0.400	0.950
A1	0.100	0.250	Q	0°	8°
B	4.800	5.100	a	0.420 TYP	
C	5.800	6.250	b	1.270 TYP	
C1	3.800	4.000			

DIP8







Dimensions In Millimeters					
Symbol :	Min :	Max :	Symbol :	Min :	Max :
A	6.100	6.680	L1	3.000	3.600
B	9.000	9.500	a	1.524 TYP	
D	8.400	9.000	b	0.889 TYP	
D1	7.420	7.820	c	0.457 TYP	
E	3.100	3.550	d	2.540 TYP	
L	0.500	0.700			

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